

# LMV98x-N 小型、低消費電力、1.8V RRIOオペアンプ、シャットダウン機能付き

## 1 特長

- 1.8V、2.7V、5Vでの仕様を保証
- 出力スイング
  - 600Ω負荷: レールから80mV
  - 2kΩ負荷: レールから30mV
- レールを200mV超える $V_{CM}$
- 消費電流(チャンネルごとに): 100μA
- ゲイン帯域幅積: 1.4MHz
- 最大 $V_{OS}$ : 4mV
- 600Ω負荷でのゲイン: 101dB
- 超小型のパッケージ: DSBGA 1.0mm×1.5mm
- シャットダウンからのターンオン時間: 19μs
- デュアルでの独立したシャットダウン
- 温度範囲: -40°C~125°C

## 2 アプリケーション

- 産業用および車載用
- 消費者向け通信機器
- フィットネス用トラッカー
- ウェアラブル
- 携帯電話/スマートフォン
- ポータブル・オーディオ
- 携帯用およびバッテリー駆動の電子機器
- 消費電流の監視
- バッテリー監視

## 3 概要

LMV98x-Nは低電圧、低消費電力のオペアンプです。LMV98x-Nは1.8V~5Vの電源電圧で動作し、入力と出力がレール・ツー・レールです。LMV98x-Nの入力同相モード電圧範囲は電源を200mV超えるため、電源電圧の範囲を超えるユーザー拡張機能が可能になります。出力は無負荷でレール・ツー・レールのスイングが可能であり、1.8V電源で600Ω負荷のとき、レールから105mV以内です。LMV98x-Nは1.8Vでの動作に最適化されているため、2つのボタン電池や単一セルのリチウムイオン・バッテリーを使用するバッテリー駆動システムに理想的です。

LMV98x-Nにはシャットダウン・ピンがあり、デバイスをディセーブルして消費電流を減らすために使用できます。 $\overline{SHDN}$ ピンがLOWのとき、デバイスはシャットダウン中です。シャットダウン時は出力が高インピーダンスになります。

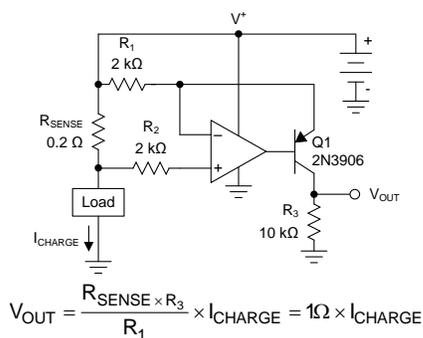
LMV98x-Nは速度/電力比が非常に優れており、1.8Vの電源電圧と小さな消費電流で、1.4MHzのゲイン帯域幅積を実現しています。LMV98x-Nは、600Ωの負荷と1000pFまでの容量性負荷を、最小のリングングで駆動できます。LMV98x-NはDCゲインが101dBと高いため、低周波数のアプリケーションに適しています。

### 製品情報<sup>(1)</sup>

型番	パッケージ	本体サイズ(公称)
LMV981-N	DSBGA (6)	1.50mm×1.30mm
	SC70 (6)	2.00mm×1.25mm
	SOT-23 (6)	2.90mm×1.60mm
LMV982-N	VSSOP (10)	3.00mm×3.00mm

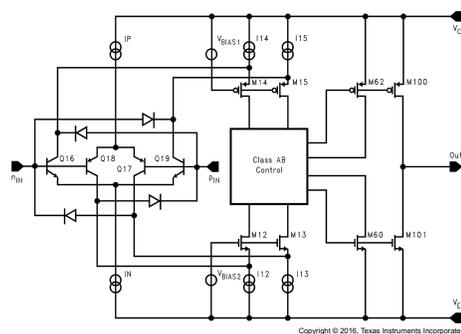
(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

### 代表的なアプリケーション



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### 概略回路図



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## 目次

<b>1</b>	<b>特長</b> .....	<b>1</b>	<b>8.2</b>	<b>Functional Block Diagram</b> .....	<b>17</b>
<b>2</b>	<b>アプリケーション</b> .....	<b>1</b>	<b>8.3</b>	<b>Feature Description</b> .....	<b>17</b>
<b>3</b>	<b>概要</b> .....	<b>1</b>	<b>8.4</b>	<b>Device Functional Modes</b> .....	<b>17</b>
<b>4</b>	<b>改訂履歴</b> .....	<b>2</b>	<b>9</b>	<b>Application and Implementation</b> .....	<b>20</b>
<b>5</b>	<b>Description (continued)</b> .....	<b>3</b>	<b>9.1</b>	<b>Application Information</b> .....	<b>20</b>
<b>6</b>	<b>Pin Configuration and Functions</b> .....	<b>3</b>	<b>9.2</b>	<b>Typical Applications</b> .....	<b>20</b>
<b>7</b>	<b>Specifications</b> .....	<b>5</b>	<b>9.3</b>	<b>Do's and Don'ts</b> .....	<b>23</b>
	7.1 Absolute Maximum Ratings .....	5	<b>10</b>	<b>Power Supply Recommendations</b> .....	<b>23</b>
	7.2 ESD Ratings .....	5	<b>11</b>	<b>Layout</b> .....	<b>24</b>
	7.3 Recommended Operating Conditions .....	5	<b>11.1</b>	<b>Layout Guidelines</b> .....	<b>24</b>
	7.4 Thermal Information .....	5	<b>11.2</b>	<b>Layout Example</b> .....	<b>24</b>
	7.5 Electrical Characteristics – DC, 1.8 V .....	6	<b>12</b>	<b>デバイスおよびドキュメントのサポート</b> .....	<b>25</b>
	7.6 Electrical Characteristics – AC, 1.8 V .....	7	<b>12.1</b>	<b>ドキュメントのサポート</b> .....	<b>25</b>
	7.7 Electrical Characteristics – DC, 2.7 V .....	8	<b>12.2</b>	<b>関連リンク</b> .....	<b>25</b>
	7.8 Electrical Characteristics – AC, 2.7 V .....	9	<b>12.3</b>	<b>ドキュメントの更新通知を受け取る方法</b> .....	<b>25</b>
	7.9 Electrical Characteristics – DC, 5 V .....	10	<b>12.4</b>	<b>コミュニティ・リソース</b> .....	<b>25</b>
	7.10 Electrical Characteristics – AC, 5 V .....	11	<b>12.5</b>	<b>商標</b> .....	<b>25</b>
	7.11 Typical Characteristics .....	12	<b>12.6</b>	<b>静電気放電に関する注意事項</b> .....	<b>25</b>
<b>8</b>	<b>Detailed Description</b> .....	<b>17</b>	<b>12.7</b>	<b>Glossary</b> .....	<b>25</b>
	8.1 Overview .....	17	<b>13</b>	<b>メカニカル、パッケージ、および注文情報</b> .....	<b>25</b>

## 4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

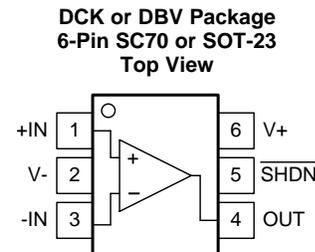
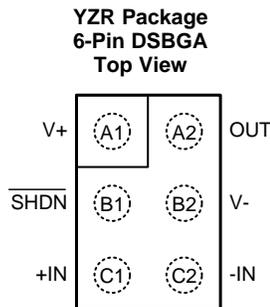
Revision L (March 2013) から Revision M に変更	Page
• 「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクション 追加 .....	1
• Changed $R_{\theta JA}$ values for LMV981-N: YZR (DSBGA) From: 286 To: 138.2 .....	5
• Changed $R_{\theta JA}$ values for LMV981-N: DCK (SC70) From: 286 To: 229.1 .....	5
• Changed $R_{\theta JA}$ values for LMV981-N: DBV (SOT-23) From: 286 To: 209.9 .....	5
• Changed $R_{\theta JA}$ values for LMV982-N: DGS (VSSOP) From: 286 To: 182.8 .....	5

Revision K (March 2013) から Revision L に変更	Page
• ナショナル・セミコンダクターのデータシートのレイアウトをTIフォーマットへ 変更 .....	1

## 5 Description (continued)

LMV981-N is offered in space-saving, 6-pin DSBGA, SC70, and SOT-23 packages. The 6-pin DSBGA package has only a 1.006 mm × 1.514 mm × 0.945 mm footprint. LMV982-N is offered in a space-saving, 10-pin VSSOP package. These small packages are ideal solutions for area constrained PCBs and portable electronics such as cellular phones and PDAs.

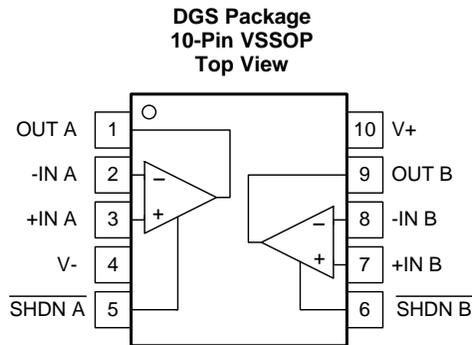
## 6 Pin Configuration and Functions



**Pin Functions: LMV981-N**

NAME	PIN		TYPE <sup>(1)</sup>	DESCRIPTION
	DSBGA	SC70, SOT-23		
+IN	C1	1	I	Noninverting input
-IN	C2	3	I	Inverting input
OUT	A2	4	O	Output
SHDN	B1	5	I	Shutdown input
V+	A1	6	P	Positive (highest) power supply
V-	B2	2	P	Negative (lowest) power supply

(1) I = Input, O = Output, P = Power


**Pin Functions: LMV982-N**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	VSSOP		
+IN A	3	I	Noninverting input, channel A
+IN B	7	I	Noninverting input, channel B
-IN A	2	I	Inverting input, channel A
-IN B	8	I	Inverting input, channel B
OUT A	1	O	Output, channel A
OUT B	9	O	Output, channel B
$\overline{\text{SHDN A}}$	5	I	Shutdown input, channel A
$\overline{\text{SHDN B}}$	6	I	Shutdown input, channel B
V+	10	P	Positive (highest) power supply
V-	4	P	Negative (lowest) power supply

(1) I = Input, O = Output, P = Power

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

	MIN	MAX	UNIT
Supply voltage (V <sup>+</sup> – V <sup>-</sup> )		5.5	V
Differential input voltage	±Supply voltage		
Voltage at input/output pins	V <sup>+</sup> + 0.3	V <sup>-</sup> - 0.3	V
Junction temperature <sup>(3)</sup>		150	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) For soldering specifications, see TI application report, [Absolute Maximum Ratings for Soldering](#) (SNOA549).
- (3) The maximum power dissipation is a function of T<sub>J(MAX)</sub>, R<sub>θJA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any ambient temperature is P<sub>D</sub> = (T<sub>J(MAX)</sub> - T<sub>A</sub>) / R<sub>θJA</sub>. All numbers apply for packages soldered directly into a PCB.

### 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
	Machine model <sup>(2)</sup>	±200	

- (1) Human Body Model, applicable std. MIL-STD-883, Method 3015.7. JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC)

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Supply voltage	1.8	5	V
Temperature	-40	125	°C

### 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	LMV981-N			LMV982-N	UNIT
	YZR (DSBGA)	DCK (SC70)	DBV (SOT-23)	DGS (VSSOP)	
	6 PINS	6 PINS	6 PINS	10 PINS	
R <sub>θJA</sub> Junction-to-ambient thermal resistance	138.2	229.1	209.9	182.8	°C/W
R <sub>θJC(top)</sub> Junction-to-case (top) thermal resistance	1.2	116.1	181.2	73.1	°C/W
R <sub>θJB</sub> Junction-to-board thermal resistance	23.4	53.3	53.2	103.3	°C/W
ψ <sub>JT</sub> Junction-to-top characterization parameter	5	8.8	55.5	12.8	°C/W
ψ <sub>JB</sub> Junction-to-board characterization parameter	23.2	52.7	52.6	101.9	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## LMV981-N, LMV982-N

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### 7.5 Electrical Characteristics – DC, 1.8 V

$T_J = 25^\circ\text{C}$ ,  $V^+ = 1.8\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT	
$V_{OS}$	Input offset voltage	LMV981-N (single)	$T_J = 25^\circ\text{C}$		1	4	mV	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$			6		
		LMV982-N (dual)	$T_J = 25^\circ\text{C}$		1	5.5		
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$					7.5
$TCV_{OS}$	Input offset voltage average drift				5.5		$\mu\text{V}/^\circ\text{C}$	
$I_B$	Input bias current	$T_J = 25^\circ\text{C}$			15	35	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				50		
$I_{OS}$	Input offset current	$T_J = 25^\circ\text{C}$			13	25	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				40		
$I_S$	Supply current (per channel)	$T_J = 25^\circ\text{C}$			103	185	$\mu\text{A}$	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				205		
		In shutdown	LMV981-N (single)	$T_J = 25^\circ\text{C}$		0.156		1
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				2
			LMV982-N (dual)	$T_J = 25^\circ\text{C}$		0.178		3.5
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				5
CMRR	Common mode rejection ratio	LMV981-N, $0\text{ V} \leq V_{CM} \leq 0.6\text{ V}$ , $1.4\text{ V} \leq V_{CM} \leq 1.8\text{ V}$ <sup>(4)</sup>		$T_J = 25^\circ\text{C}$	60	78	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		55		
		LMV982, $0\text{ V} \leq V_{CM} \leq 0.6\text{ V}$ , $1.4\text{ V} \leq V_{CM} \leq 1.8\text{ V}$ <sup>(4)</sup>		$T_J = 25^\circ\text{C}$	55	76		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		50		
		$-0.2\text{ V} \leq V_{CM} \leq 0\text{ V}$ , $1.8\text{ V} \leq V_{CM} \leq 2\text{ V}$			50	72		
PSRR	Power supply rejection ratio	$1.8\text{ V} \leq V^+ \leq 5\text{ V}$		$T_J = 25^\circ\text{C}$	75	100	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		70		
CMVR	Input common-mode voltage	For CMRR range $\geq 50\text{ dB}$		$T_A = 25^\circ\text{C}$	$V^- - 0.2$	$-0.2$	V	
				$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$	$V^-$	$V^+$		
				$T_A = 125^\circ\text{C}$	$V^- + 0.2$	$V^+ - 0.2$		
$A_V$	Large signal voltage gain LMV981-N (single)	$R_L = 600\ \Omega$ to $0.9\text{ V}$ , $V_O = 0.2\text{ V}$ to $1.6\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	77	101	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		73		
		$R_L = 2\text{ k}\Omega$ to $0.9\text{ V}$ , $V_O = 0.2\text{ V}$ to $1.6\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	80	105		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		75		
	Large signal voltage gain LMV982-N (dual)	$R_L = 600\ \Omega$ to $0.9\text{ V}$ , $V_O = 0.2\text{ V}$ to $1.6\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	75	90	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		72		
		$R_L = 2\text{ k}\Omega$ to $0.9\text{ V}$ , $V_O = 0.2\text{ V}$ to $1.6\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	78	100		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		75		

- (1) Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are specified by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- (4) For ensured temperature ranges, see input common-mode voltage range specifications.

## Electrical Characteristics – DC, 1.8 V (continued)

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 1.8\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT			
$V_O$	Output swing	$R_L = 600\ \Omega$ to $0.9\text{ V}$ , $V_{IN} = \pm 100\text{ mV}$	$T_J = 25^\circ\text{C}$	1.65	1.72		V		
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		0.077	0.105			
		$R_L = 2\text{ k}\Omega$ to $0.9\text{ V}$ , $V_{IN} = \pm 100\text{ mV}$	$T_J = 25^\circ\text{C}$	1.75	1.77				
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	1.74		0.04			
		$I_O$	Output short circuit current <sup>(5)</sup>	Sourcing, $V_O = 0\text{ V}$ , $V_{IN} = 100\text{ mV}$	$T_J = 25^\circ\text{C}$	4		8	mA
					$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	3.3			
Sinking, $V_O = 1.8\text{ V}$ , $V_{IN} = -100\text{ mV}$	$T_J = 25^\circ\text{C}$			7	9				
	$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$			5					
$T_{on}$	Turnon time from shutdown		19		$\mu\text{s}$				
$V_{SHDN}$	Turnon voltage to enable part		1		V				
	Turnoff voltage		0.55						

(5) Applies to both single-supply and split-supply operation. Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of  $45\text{ mA}$  over long term may adversely affect reliability.

## 7.6 Electrical Characteristics – AC, 1.8 V

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 1.8\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
SR	Slew rate <sup>(4)</sup>			0.35		$\text{V}/\mu\text{s}$
GBW	Gain-bandwidth product			1.4		MHz
$\Phi_m$	Phase margin			67		$^\circ$
$G_m$	Gain margin			7		dB
$e_n$	Input-referred voltage noise	$f = 10\text{ kHz}$ , $V_{CM} = 0.5\text{ V}$		60		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-referred current noise	$f = 10\text{ kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$ , $A_V = +1$ , $R_L = 600\ \Omega$ , $V_{IN} = 1\text{ V}_{PP}$		0.023%		
	Amp-to-amp isolation <sup>(5)</sup>			123		dB

- Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- All limits are specified by testing or statistical analysis.
- Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.
- Input referred,  $R_L = 100\text{ k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with  $1\text{ kHz}$  to produce  $V_O = 3\text{ V}_{PP}$  (for supply voltages  $< 3\text{ V}$ ,  $V_O = V^+$ ).

## 7.7 Electrical Characteristics – DC, 2.7 V

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 2.7\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT	
$V_{OS}$	Input offset voltage	LMV981-N (single)	$T_J = 25^\circ\text{C}$		1	4	mV	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$			6		
		LMV982-N (dual)	$T_J = 25^\circ\text{C}$		1	6	mV	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$					7.5
$TCV_{OS}$	Input offset voltage average drift				5.5		$\mu\text{V}/^\circ\text{C}$	
$I_B$	Input bias current	$T_J = 25^\circ\text{C}$			15	35	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				50		
$I_{OS}$	Input offset current	$T_J = 25^\circ\text{C}$			8	25	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				40		
$I_S$	Supply current (per channel)	$T_J = 25^\circ\text{C}$			105	190	$\mu\text{A}$	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				210		
		In shutdown	LMV981-N (single)	$T_J = 25^\circ\text{C}$		0.061		1
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				2
			LMV982-N (dual)	$T_J = 25^\circ\text{C}$		0.101		3.5
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				5
CMRR	Common mode rejection ratio	LMV981-N, $0\text{ V} \leq V_{CM} \leq 1.5\text{ V}$ , $2.3\text{ V} \leq V_{CM} \leq 2.7\text{ V}$ <sup>(4)</sup>		$T_J = 25^\circ\text{C}$	60	81	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		55		
		LMV982, $0\text{ V} \leq V_{CM} \leq 1.5\text{ V}$ , $2.3\text{ V} \leq V_{CM} \leq 2.7\text{ V}$ <sup>(4)</sup>		$T_J = 25^\circ\text{C}$	55	80		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		50		
		$-0.2\text{ V} \leq V_{CM} \leq 0\text{ V}$ , $2.7\text{ V} \leq V_{CM} \leq 2.9\text{ V}$			50	74		
PSRR	Power supply rejection ratio	$1.8\text{ V} \leq V^+ \leq 5\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	75	100	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		70		
CMVR	Input common mode voltage	For CMRR Range $\geq 50\text{ dB}$		$T_A = 25^\circ\text{C}$	$V^- - 0.2$	$-0.2$	V	
				$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$	$V^-$	$V^+ + 0.2$		
				$T_A = 125^\circ\text{C}$	$V^- + 0.2$	$V^+ - 0.2$		
$A_V$	Large signal voltage gain LMV981-N (single)	$R_L = 600\ \Omega$ to $1.35\text{ V}$ , $V_O = 0.2\text{ V}$ to $2.5\text{ V}$		$T_J = 25^\circ\text{C}$	87	104	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		86		
		$R_L = 2\text{ k}\Omega$ to $1.35\text{ V}$ , $V_O = 0.2\text{ V}$ to $2.5\text{ V}$		$T_J = 25^\circ\text{C}$	92	110		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		91		
	Large signal voltage gain LMV982-N (dual)	$R_L = 600\ \Omega$ to $1.35\text{ V}$ , $V_O = 0.2\text{ V}$ to $2.5\text{ V}$		$T_J = 25^\circ\text{C}$	78	90		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		75		
		$R_L = 2\text{ k}\Omega$ to $1.35\text{ V}$ , $V_O = 0.2\text{ V}$ to $2.5\text{ V}$		$T_J = 25^\circ\text{C}$	81	100		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		78		

- (1) Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are specified by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- (4) For ensured temperature ranges, see input common mode voltage range specifications.

## Electrical Characteristics – DC, 2.7 V (continued)

$T_J = 25^\circ\text{C}$ ,  $V^+ = 2.7\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{\text{CM}} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
$V_O$	Output swing	$R_L = 600\ \Omega$ to $1.35\text{ V}$ , $V_{\text{IN}} = \pm 100\text{ mV}$	$T_J = 25^\circ\text{C}$	2.55	2.62		V
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		0.083	0.11	
			$T_J = 25^\circ\text{C}$	2.53		0.13	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	2.65	2.675		
		$R_L = 2\text{ k}\Omega$ to $1.35\text{ V}$ , $V_{\text{IN}} = \pm 100\text{ mV}$	$T_J = 25^\circ\text{C}$		0.025	0.04	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	2.64		0.045	
$I_O$	Output short circuit current <sup>(5)</sup>	Sourcing, $V_O = 0\text{ V}$ , $V_{\text{IN}} = 100\text{ mV}$	$T_J = 25^\circ\text{C}$	20	30		mA
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	15			
		Sinking, $V_O = 0\text{ V}$ , $V_{\text{IN}} = -100\text{ mV}$	$T_J = 25^\circ\text{C}$	18	25		
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	12			
$T_{\text{on}}$	Turnon time from shutdown			12.5		$\mu\text{s}$	
$V_{\text{SHDN}}$	Turnon voltage to enable part			1.9		V	
	Turnoff voltage			0.8			

(5) Applies to both single-supply and split-supply operation. Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of  $45\text{ mA}$  over long term may adversely affect reliability.

## 7.8 Electrical Characteristics – AC, 2.7 V

$T_J = 25^\circ\text{C}$ ,  $V^+ = 2.7\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{\text{CM}} = 1\text{ V}$ ,  $V_O = 1.35\text{ V}$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
SR	Slew rate <sup>(4)</sup>				0.4		$\text{V}/\mu\text{s}$
GBW	Gain-bandwidth product				1.4		MHz
$\Phi_m$	Phase margin				70		$^\circ$
$G_m$	Gain margin				7.5		dB
$e_n$	Input-referred voltage noise	$f = 10\text{ kHz}$ , $V_{\text{CM}} = 0.5\text{ V}$			57		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-referred current noise	$f = 10\text{ kHz}$			0.08		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$ , $A_V = +1$ , $R_L = 600\ \Omega$ , $V_{\text{IN}} = 1\text{ V}_{\text{PP}}$			0.022%		
	Amp-to-amp isolation <sup>(5)</sup>				123		dB

- (1) Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are specified by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- (4) Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.
- (5) Input referred,  $R_L = 100\text{ k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with  $1\text{ kHz}$  to produce  $V_O = 3\text{ V}_{\text{PP}}$  (for supply voltages  $< 3\text{ V}$ ,  $V_O = V^+$ ).

## 7.9 Electrical Characteristics – DC, 5 V

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 5\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT	
$V_{OS}$	Input offset voltage	LMV981-N (single)	$T_J = 25^\circ\text{C}$		1	4	mV	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$			6		
		LMV982-N (dual)	$T_J = 25^\circ\text{C}$		1	5.5		
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$					7.5
$TCV_{OS}$	Input offset voltage average drift				5.5		$\mu\text{V}/^\circ\text{C}$	
$I_B$	Input bias current	$T_J = 25^\circ\text{C}$			14	35	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				50		
$I_{OS}$	Input offset current	$T_J = 25^\circ\text{C}$			9	25	nA	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				40		
$I_S$	Supply current (per channel)	$T_J = 25^\circ\text{C}$			116	210	$\mu\text{A}$	
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				230		
		In shutdown	LMV981-N (single)	$T_J = 25^\circ\text{C}$		0.201	1	$\mu\text{A}$
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				
	LMV982-N (dual)	$T_J = 25^\circ\text{C}$		0.302	3.5			
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				5		
$CMRR$	Common mode rejection ratio <sup>(4)</sup>	$0\text{ V} \leq V_{CM} \leq 3.8\text{ V}$ , $4.6\text{ V} \leq V_{CM} \leq 5\text{ V}$		$T_J = 25^\circ\text{C}$	60	86	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	55			
		$-0.2\text{ V} \leq V_{CM} \leq 0\text{ V}$ , $5\text{ V} \leq V_{CM} \leq 5.2\text{ V}$			50	78		
$PSRR$	Power supply rejection ratio	$1.8\text{ V} \leq V^+ \leq 5\text{ V}$ , $V_{CM} = 0.5\text{ V}$		$T_J = 25^\circ\text{C}$	75	100	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	70			
$CMVR$	Input common mode voltage	For CMRR range $\geq 50\text{ dB}$		$T_A = 25^\circ\text{C}$	$V^- - 0.2$	$-0.2$	V	
				$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$	$V^-$	$V^+ + 0.2$		
				$T_A = 125^\circ\text{C}$	$V^- + 0.3$	$V^+ - 0.3$		
$A_V$	Large signal voltage gain LMV981-N (single)	$R_L = 600\ \Omega$ to $2.5\text{ V}$ , $V_O = 0.2\text{ V}$ to $4.8\text{ V}$		$T_J = 25^\circ\text{C}$	88	102	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	87			
		$R_L = 2\text{ k}\Omega$ to $2.5\text{ V}$ , $V_O = 0.2\text{ V}$ to $4.8\text{ V}$		$T_J = 25^\circ\text{C}$	94	113		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	93			
	Large signal voltage gain LMV982-N (dual)	$R_L = 600\ \Omega$ to $2.5\text{ V}$ , $V_O = 0.2\text{ V}$ to $4.8\text{ V}$		$T_J = 25^\circ\text{C}$	81	90	dB	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	78			
$R_L = 2\text{ k}\Omega$ to $2.5\text{ V}$ , $V_O = 0.2\text{ V}$ to $4.8\text{ V}$		$T_J = 25^\circ\text{C}$	85	100				
		$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	82					
$V_O$	Output swing	$R_L = 600\ \Omega$ to $2.5\text{ V}$ , $V_{IN} = \pm 100\text{ mV}$		$T_J = 25^\circ\text{C}$	4.855	4.89	V	
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	4.835	0.12		0.16
		$R_L = 2\text{ k}\Omega$ to $2.5\text{ V}$ , $V_{IN} = \pm 100\text{ mV}$		$T_J = 25^\circ\text{C}$	4.945	4.967		
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	4.935	0.037		0.065
				$T_J = 25^\circ\text{C}$				0.075
				$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$				

- Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- All limits are specified by testing or statistical analysis.
- Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- For ensured temperature ranges, see input common mode voltage range specifications.

## Electrical Characteristics – DC, 5 V (continued)

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 5\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
$I_O$	Output short-circuit current <sup>(5)</sup>	LMV981-N, sourcing, $V_O = 0\text{ V}$ , $V_{IN} = 100\text{ mV}$	$T_J = 25^\circ\text{C}$	80	100	mA
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	68		
		Sinking, $V_O = 5\text{ V}$ , $V_{IN} = -100\text{ mV}$	$T_J = 25^\circ\text{C}$	58	65	
			$T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$	45		
$T_{on}$	Turnon time from shutdown		8.4		$\mu\text{s}$	
$V_{SHDN}$	Turnon voltage to enable part		4.2		V	
	Turnoff voltage		0.8			

(5) Applies to both single-supply and split-supply operation. Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of 45 mA over long term may adversely affect reliability.

## 7.10 Electrical Characteristics – AC, 5 V

 $T_J = 25^\circ\text{C}$ ,  $V^+ = 5\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = 2.5\text{ V}$ ,  $R_L > 1\text{ M}\Omega$ , and  $\overline{\text{SHDN}}$  tied to  $V^+$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
SR	Slew rate <sup>(4)</sup>			0.42		V/ $\mu\text{s}$
GBW	Gain-bandwidth product			1.5		MHz
$\Phi_m$	Phase margin			71		$^\circ$
$G_m$	Gain margin			8		dB
$e_n$	Input-referred voltage noise	$f = 10\text{ kHz}$ , $V_{CM} = 1\text{ V}$		50		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-referred current noise	$f = 10\text{ kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$ , $A_V = +1$ , $R_L = 600\ \Omega$ , $V_O = 1\text{ V}_{PP}$		0.022%		
	Amp-to-amp isolation <sup>(5)</sup>			123		dB

- Electrical characteristics table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . *Absolute Maximum Ratings* indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- All limits are specified by testing or statistical analysis.
- Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.
- Input referred,  $R_L = 100\text{ k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with 1 kHz to produce  $V_O = 3\text{ V}_{PP}$  (for supply voltages  $< 3\text{ V}$ ,  $V_O = V^+$ ).

LMV981-N, LMV982-N

JAJ972M – NOVEMBER 2001 – REVISED SEPTEMBER 2016

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7.11 Typical Characteristics

$V_S = 5\text{ V}$ , single supply, and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

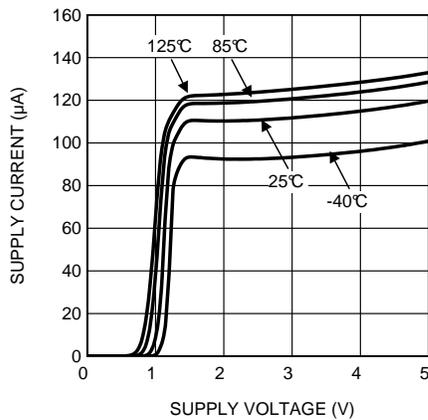


Figure 1. Supply Current vs Supply Voltage (LMV981-N)

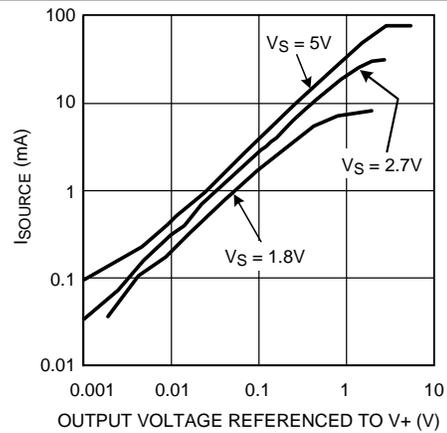


Figure 2. Sourcing Current vs Output Voltage

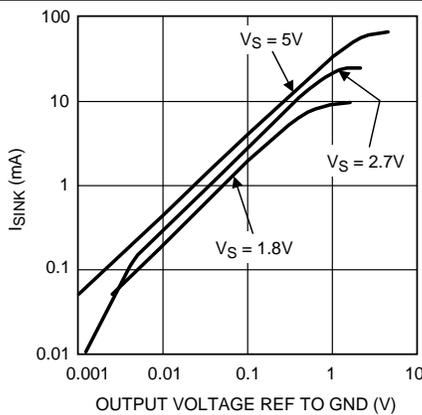


Figure 3. Sinking Current vs Output Voltage

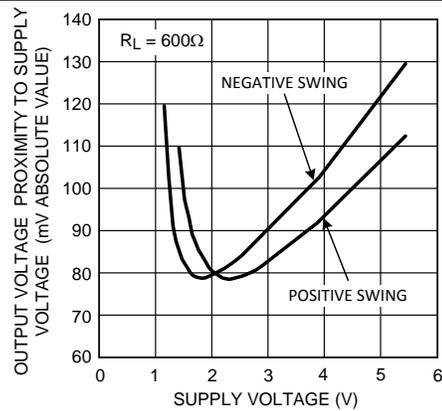


Figure 4. Output Voltage Swing vs Supply Voltage

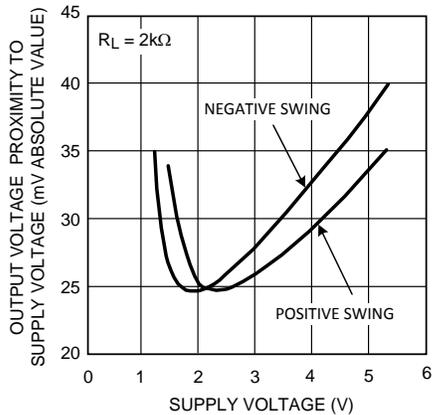


Figure 5. Output Voltage Swing vs Supply Voltage

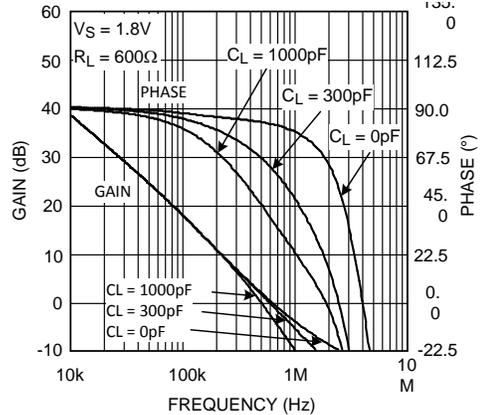


Figure 6. Gain and Phase vs Frequency

Typical Characteristics (continued)

$V_S = 5\text{ V}$ , single supply, and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

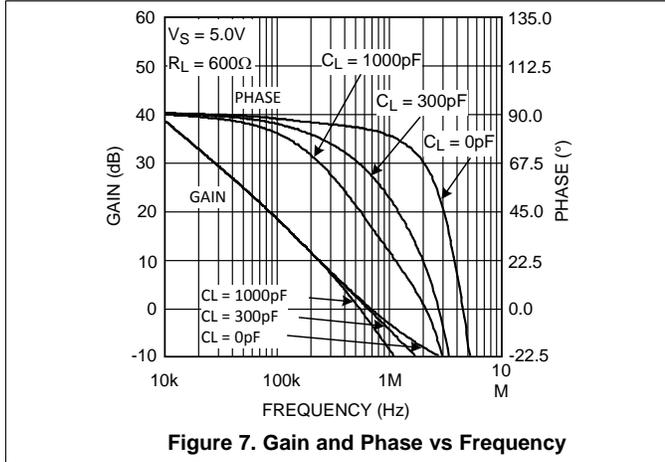


Figure 7. Gain and Phase vs Frequency

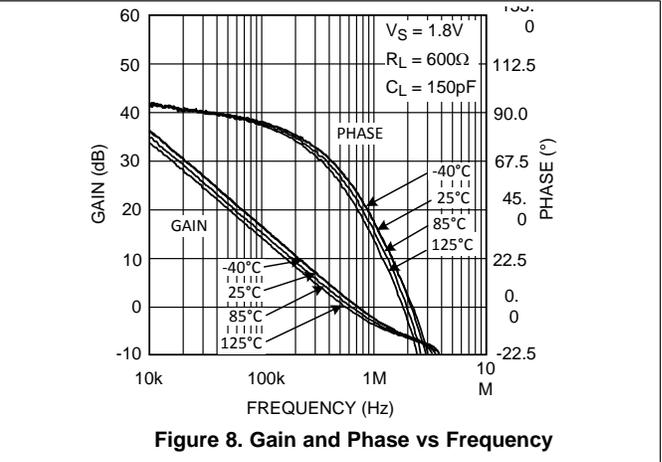


Figure 8. Gain and Phase vs Frequency

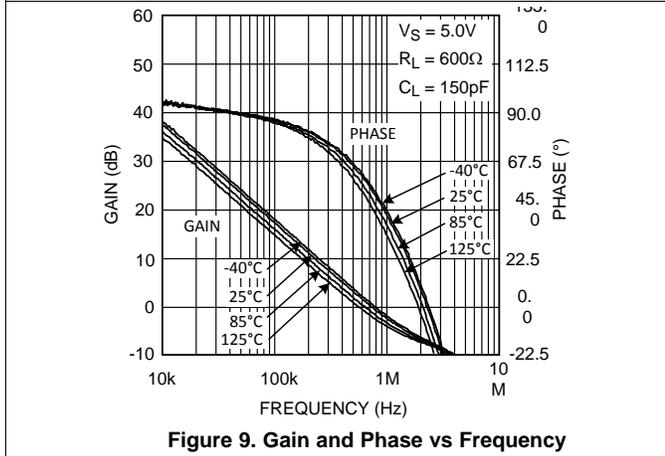


Figure 9. Gain and Phase vs Frequency

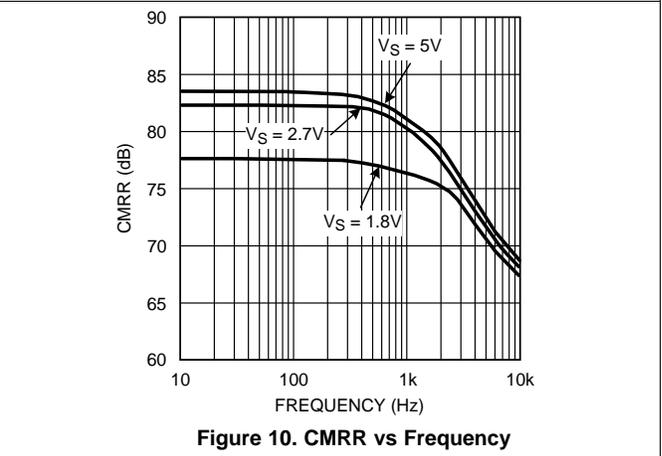


Figure 10. CMRR vs Frequency

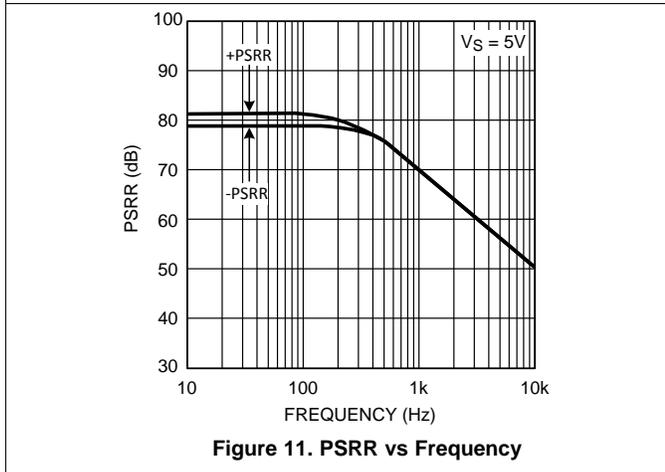


Figure 11. PSRR vs Frequency

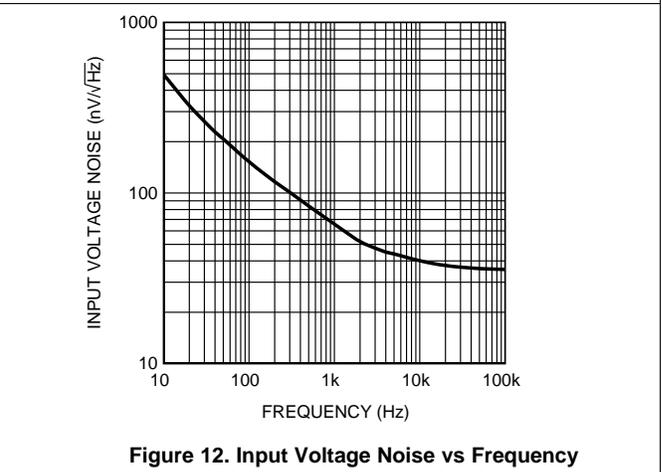
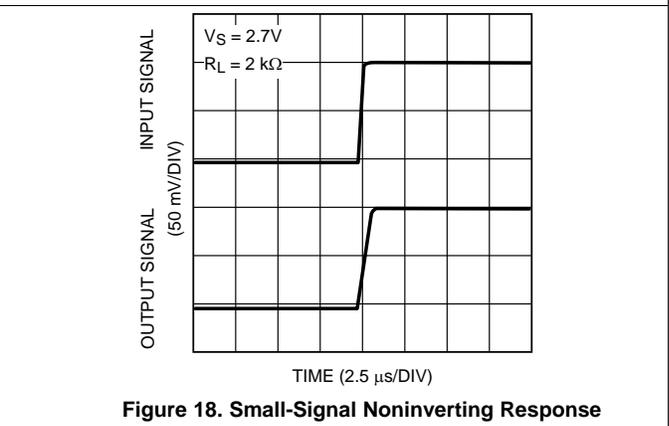
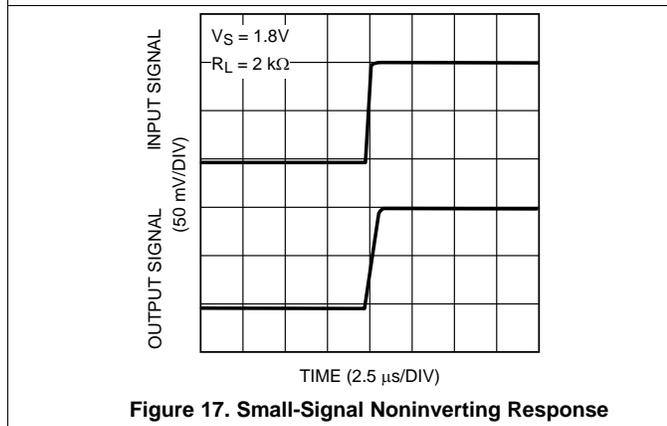
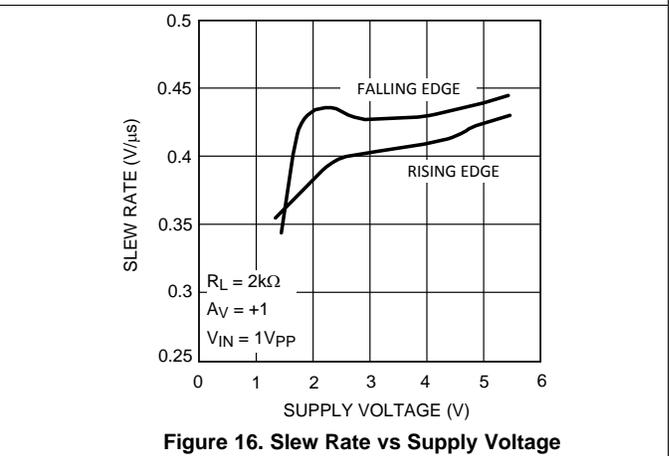
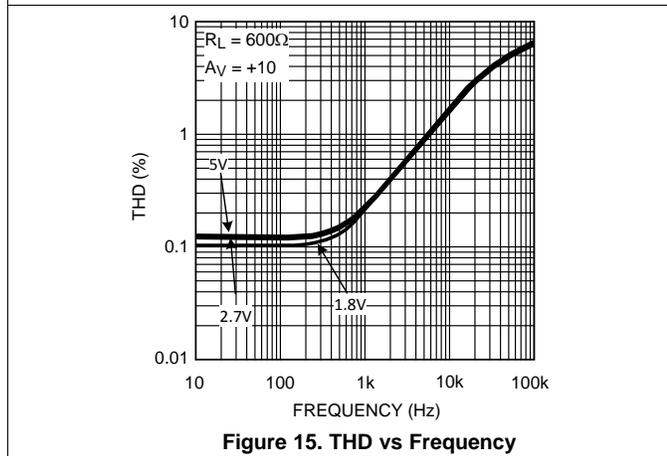
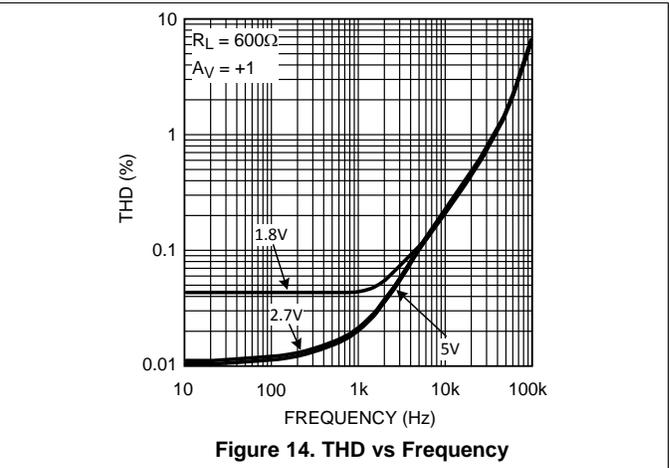
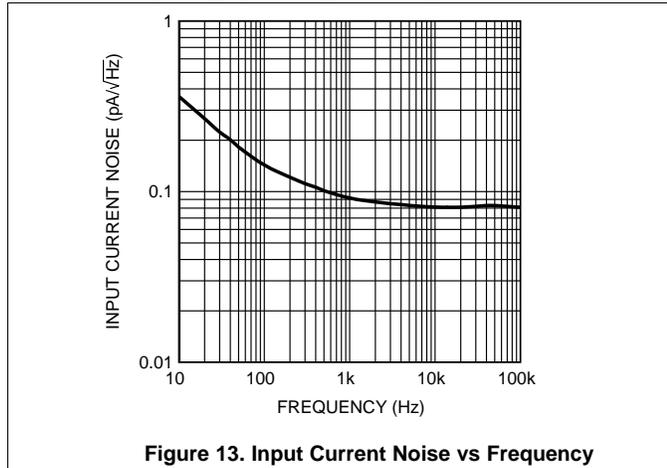


Figure 12. Input Voltage Noise vs Frequency

Typical Characteristics (continued)

$V_S = 5\text{ V}$ , single supply, and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)



Typical Characteristics (continued)

$V_S = 5\text{ V}$ , single supply, and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

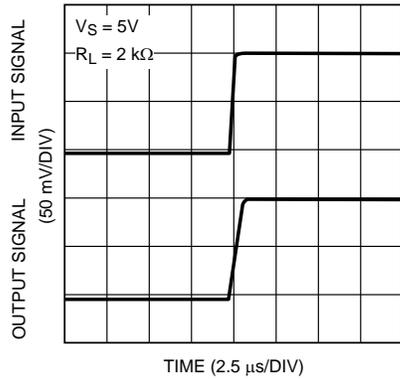


Figure 19. Small-Signal Noninverting Response

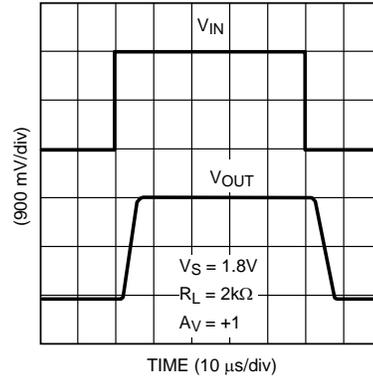


Figure 20. Large-Signal Noninverting Response

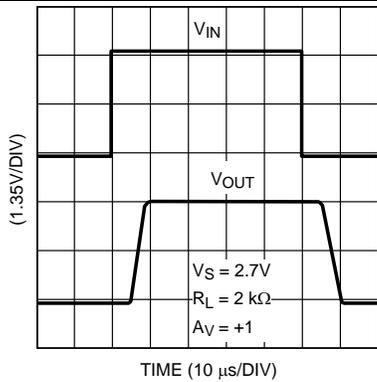


Figure 21. Large-Signal Noninverting Response

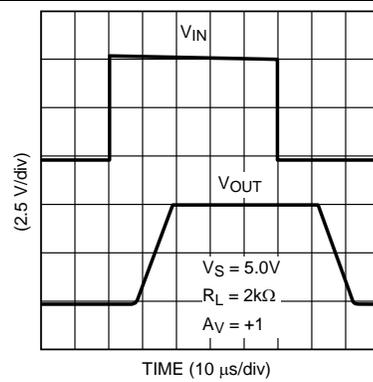


Figure 22. Large-Signal Noninverting Response

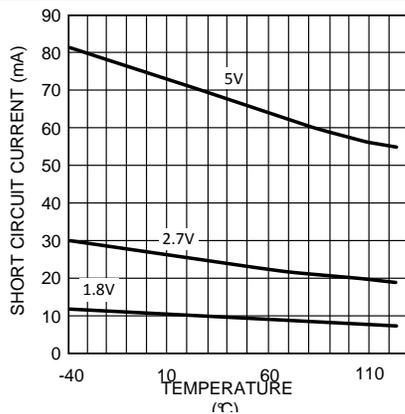


Figure 23. Short-Circuit Current vs Temperature (Sinking)

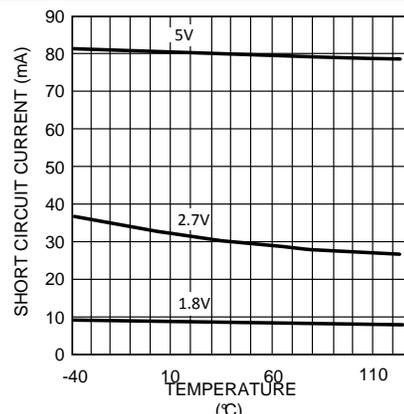
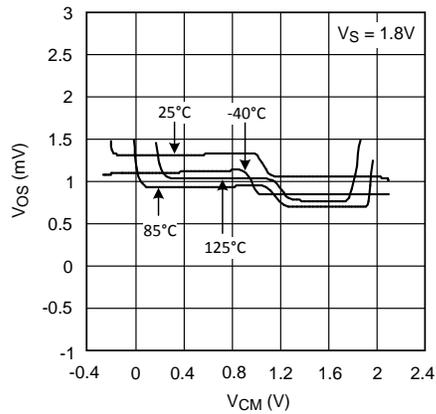
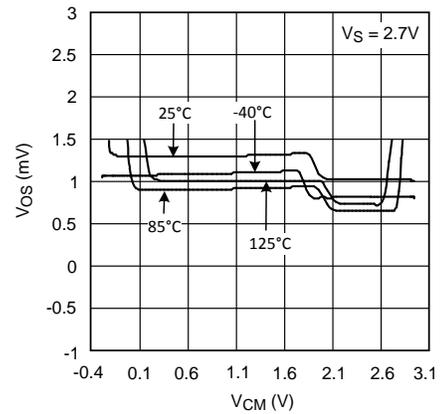
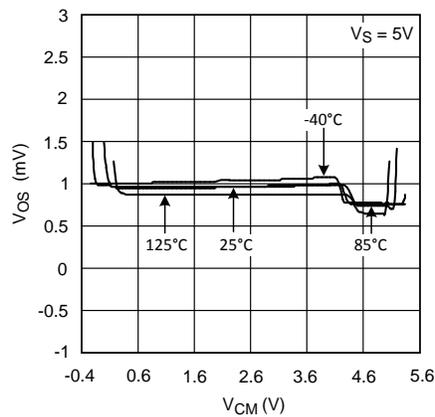


Figure 24. Short-Circuit Current vs Temperature (Sourcing)

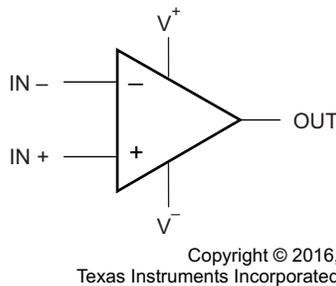
**Typical Characteristics (continued)**
 $V_S = 5\text{ V}$ , single supply, and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

**Figure 25. Offset Voltage vs Common Mode Range**

**Figure 26. Offset Voltage vs Common Mode Range**

**Figure 27. Offset Voltage vs Common Mode Range**

## 8 Detailed Description

### 8.1 Overview

The LMV98x-N are low-voltage, low-power operational amplifiers (op-amp) operating from 1.8-V to 5.5-V supply voltages and have rail-to-rail input and output with shutdown. LMV98x-N input common-mode voltage extends 200 mV beyond the supplies which enables user enhanced functionality beyond the supply voltage range.

### 8.2 Functional Block Diagram



(each amplifier)

### 8.3 Feature Description

The differential inputs of the amplifier consist of a noninverting input (+IN) and an inverting input (-IN). The amplifier amplifies only the difference in voltage between the two inputs, which is called the differential input voltage. The output voltage of the op-amp  $V_{OUT}$  is given by [Equation 1](#):

$$V_{OUT} = A_{OL} (IN^+ - IN^-)$$

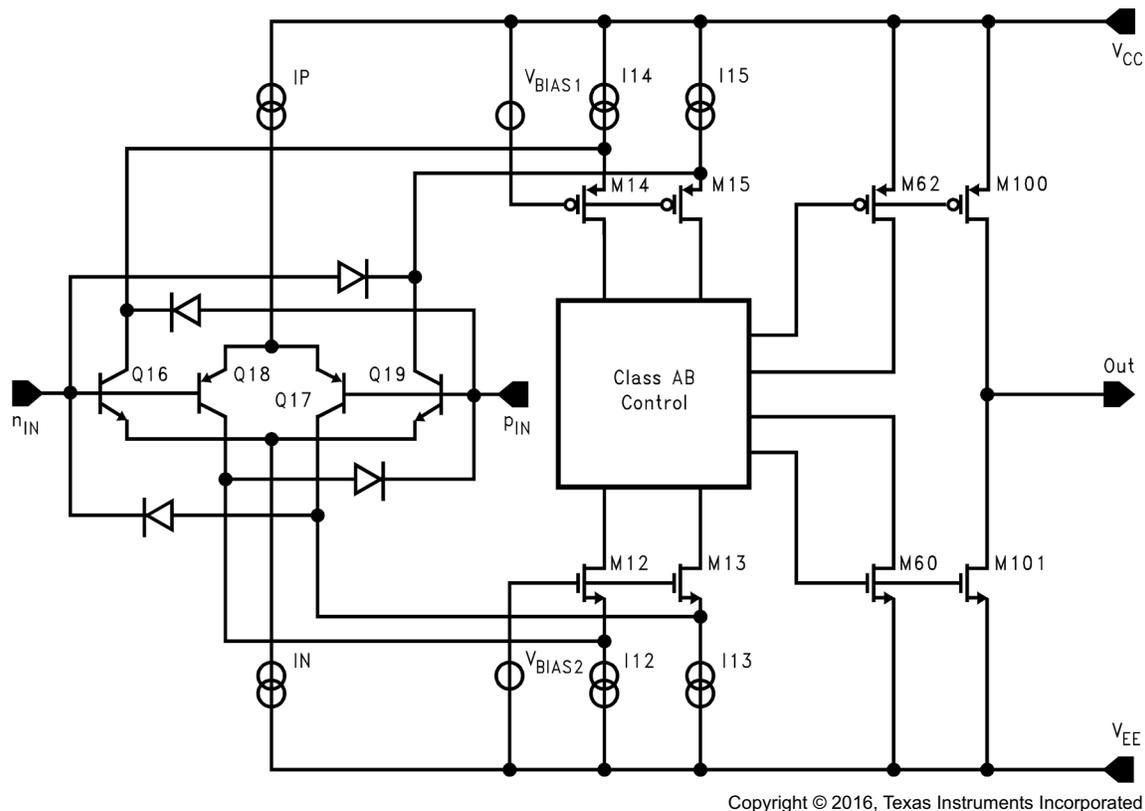
where

- $A_{OL}$  is the open-loop gain of the amplifier, typically around 100 dB (100,000x, or 10  $\mu$ V per volt). (1)

### 8.4 Device Functional Modes

#### 8.4.1 Input and Output Stage

The rail-to-rail input stage of this family provides more flexibility for the designer. The LMV98x-N use a complimentary PNP and NPN input stage in which the PNP stage senses common-mode voltage near  $V^-$  and the NPN stage senses common-mode voltage near  $V^+$ . The transition from the PNP stage to NPN stage occurs 1 V below  $V^+$ . Because both input stages have their own offset voltage, the offset of the amplifier becomes a function of the input common-mode voltage and has a crossover point at 1 V below  $V^+$ .

**Device Functional Modes (continued)**

**Figure 28. Simplified Schematic Diagram**

This  $V_{OS}$  crossover point can create problems for both DC- and AC-coupled signals if proper care is not taken. Large input signals that include the  $V_{OS}$  crossover point causes distortion in the output signal. One way to avoid such distortion is to keep the signal away from the crossover. For example, in a unity gain buffer configuration with  $V_S = 5\text{ V}$ , a 5-V peak-to-peak signal centered at 1.5 V does not contain input-crossover distortion while a 3-V peak-to-peak signal centered at 1.5 V does contain input-crossover distortion. Another way to avoid large signal distortion is to use a gain of  $-1$  circuit which avoids any voltage excursions at the input terminals of the amplifier. In that circuit, the common-mode DC voltage can be set at a level away from the  $V_{OS}$  cross-over point. For small signals, this transition in  $V_{OS}$  shows up as a  $V_{CM}$  dependent spurious signal in series with the input signal and can effectively degrade small-signal parameters such as gain and common-mode rejection ratio. To resolve this problem, the small signal must be placed such that it avoids the  $V_{OS}$  crossover point. In addition to the rail-to-rail performance, the output stage can provide enough output current to drive 600- $\Omega$  loads. Because of the high-current capability, take care not to exceed the 150°C maximum junction temperature specification.

**8.4.2 Shutdown Mode**

The LMV98x-N family has a shutdown pin. To conserve battery life in portable applications, the LMV98x-N can be disabled when the shutdown pin voltage is pulled low. When in shutdown, the output stage is in a high-impedance state and the input bias current drops to less than 1 nA.

The shutdown pin cannot be left unconnected. In case shut-down operation is not required, the shutdown pin must be connected to  $V+$  when the LMV98x-N are used. Leaving the shutdown pin floating results in an undefined operation mode, either shutdown or active, or even oscillating between the two modes.

## Device Functional Modes (continued)

### 8.4.3 Input Bias Current Consideration

The LMV98x-N family has a complementary bipolar input stage. The typical input bias current ( $I_B$ ) is 15 nA. The input bias current can develop a significant offset voltage. This offset is primarily due to  $I_B$  flowing through the negative feedback resistor,  $R_F$ . For example, if  $I_B$  is 50 nA and  $R_F$  is 100 k $\Omega$ , then an offset voltage of 5 mV develops ( $V_{OS} = I_B \times R_F$ ). Using a compensation resistor ( $R_C$ ), as shown in Figure 29, cancels this effect. But the input offset current ( $I_{OS}$ ) still contributes to an offset voltage in the same manner.

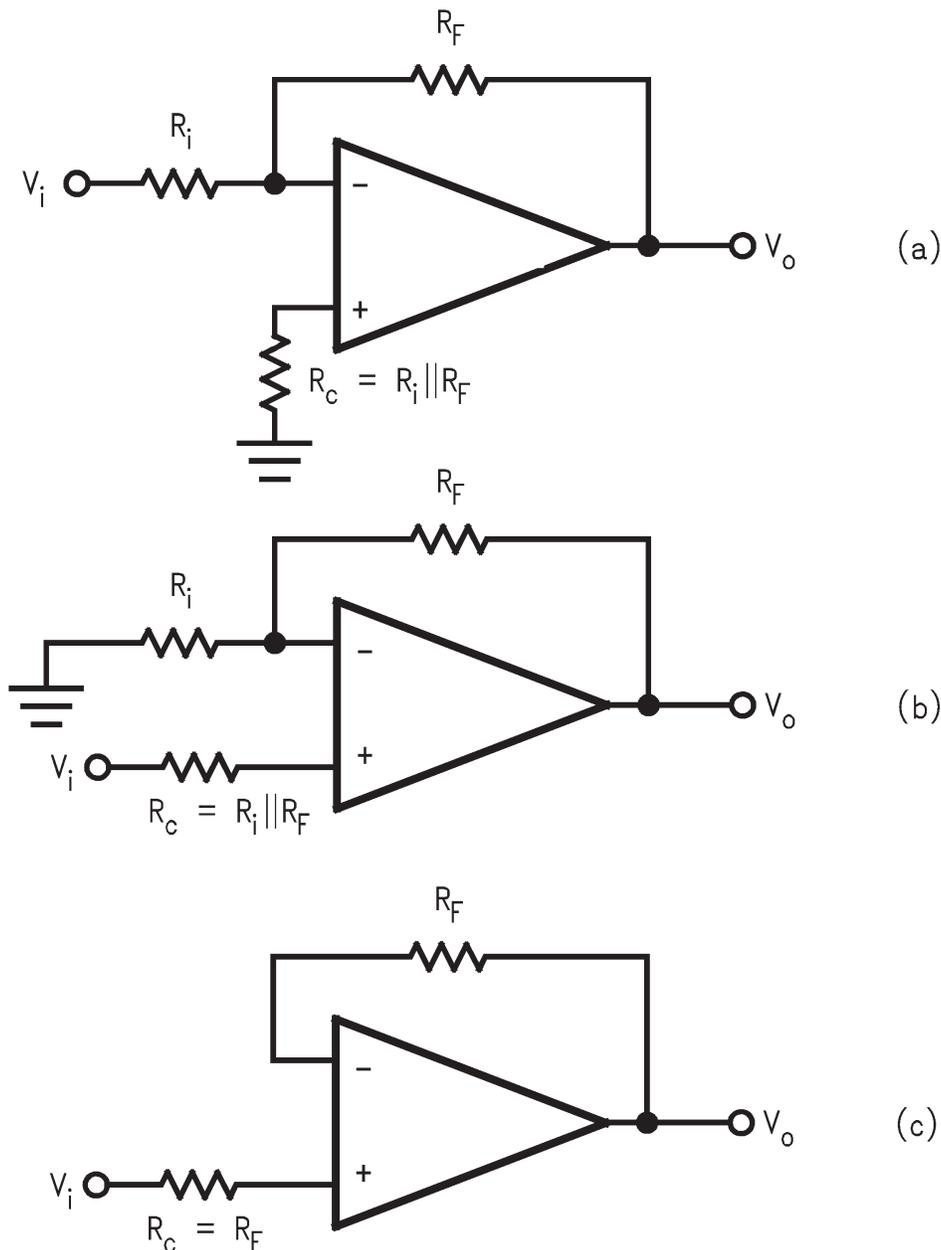


Figure 29. Canceling the Offset Voltage due to Input Bias Current

## 9 Application and Implementation

### NOTE

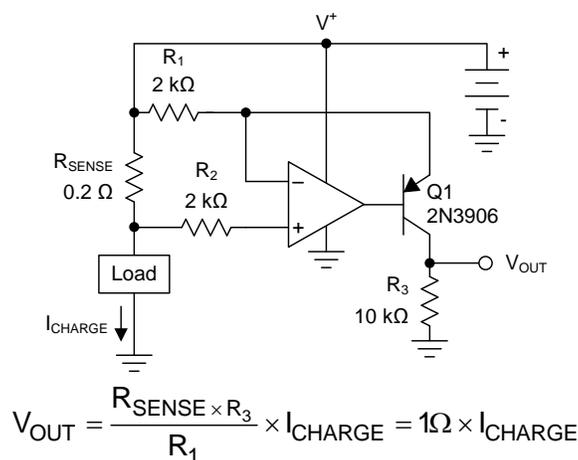
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The LMV98x-N devices bring performance, economy, and ease-of-use to low-voltage, low-power systems. They provide rail-to-rail input and rail-to-rail output swings into heavy loads.

### 9.2 Typical Applications

#### 9.2.1 High-Side Current-Sensing Application



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**Figure 30. High-Side Current Sensing**

##### 9.2.1.1 Design Requirements

The high-side current-sensing circuit (Figure 30) is commonly used in a battery charger to monitor charging current to prevent overcharging. A sense resistor  $R_{SENSE}$  is connected to the battery directly. This system requires an op amp with rail-to-rail input. The LMV98x-N are ideal for this application because its common-mode input range extends up to the positive supply.

##### 9.2.1.2 Detailed Design Procedure

As seen in Figure 30, the  $I_{CHARGE}$  current flowing through sense resistor  $R_{SENSE}$  develops a voltage drop equal to  $V_{SENSE}$ . The voltage at the negative sense point is now less than the positive sense point by an amount proportional to the  $V_{SENSE}$  voltage.

The low-bias currents of the LMV98x cause little voltage drop through  $R_2$ , so the negative input of the LMV98x amplifier is at essentially the same potential as the negative sense input.

The LMV98x detects this voltage error between its inputs and servo the transistor base to conduct more current through Q1, increasing the voltage drop across  $R_1$  until the LMV98x inverting input matches the noninverting input. At this point, the voltage drop across  $R_1$  now matches  $V_{SENSE}$ .

$I_G$ , a current proportional to  $I_{CHARGE}$ , flows according to Equation 2.

$$I_G = V_{SENSE} / R_1 = (R_{SENSE} \times I_{CHARGE}) / R_1 \quad (2)$$

### Typical Applications (continued)

$I_G$  also flows through the gain resistor  $R_3$  developing a voltage drop equal to [Equation 3](#) and [Equation 4](#).

$$V_3 = I_G \times R_3 = (V_{RSENSE} / R_1) \times R_3 = ((R_{SENSE} \times I_{CHARGE}) / R_2) \times R_3 \quad (3)$$

$$V_{OUT} = (R_{SENSE} \times I_{CHARGE}) \times G$$

where

- $G = R_3 / R_1$  (4)

The other channel of the LMV98x may be used to buffer the voltage across  $R_3$  to drive the following stages.

#### 9.2.1.3 Application Curve

[Figure 31](#) shows the results of the example current sense circuit. After 4 V, there is an error where transistor Q1 runs out of headroom and saturates, limiting the upper output swing.

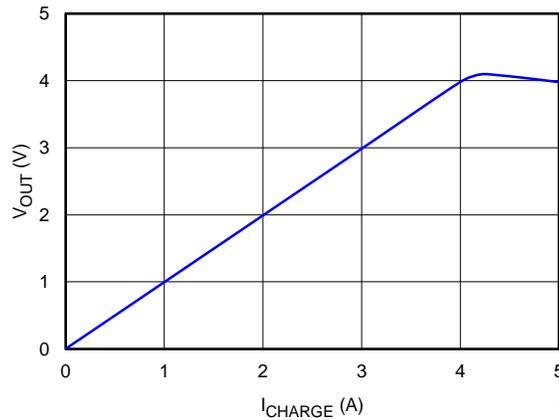


Figure 31. Current Sense Amplifier Results

### 9.2.2 Half-Wave Rectifier Applications

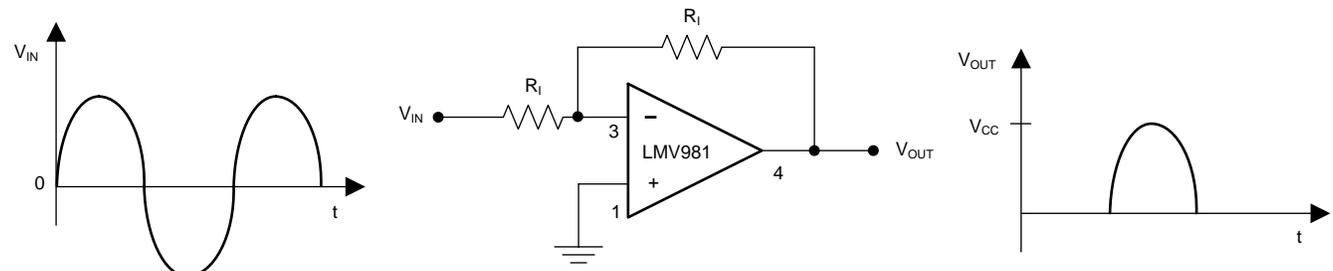


Figure 32. Half-Wave Rectifier With Rail-To-Ground Output Swing Referenced to Ground

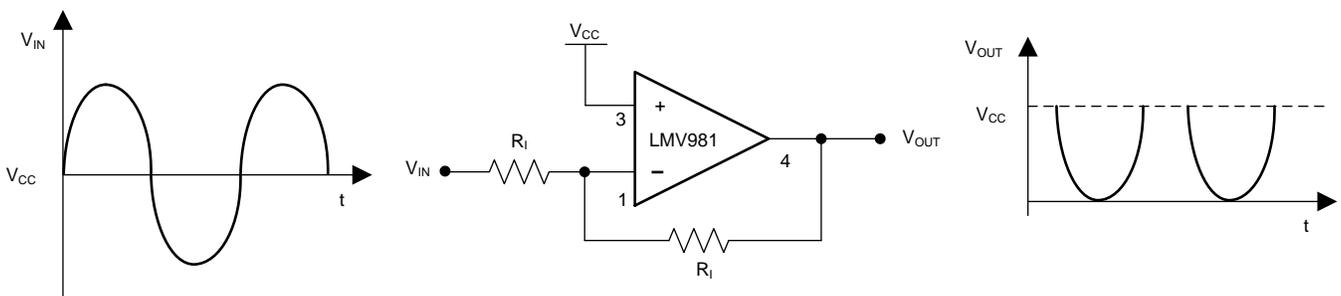


Figure 33. Half-Wave Rectifier With Negative-Going Output Referenced to  $V_{CC}$

## Typical Applications (continued)

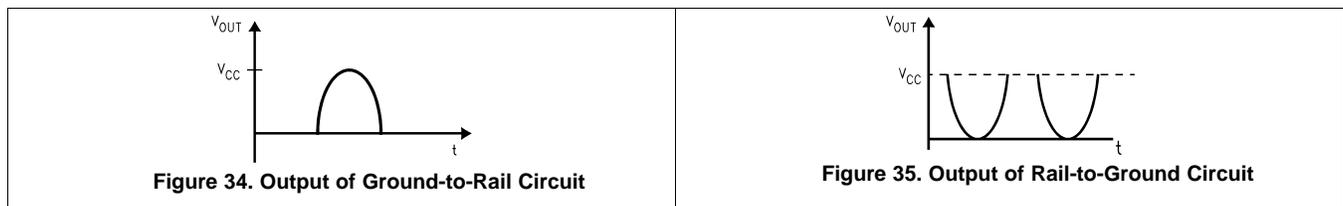
### 9.2.2.1 Design Requirements

Because the LMV98x-N input common-mode range includes both positive and negative supply rails and the output can also swing to either supply, achieving half-wave rectifier functions in either direction is an easy task. All that is required are two external resistors; there is no requirement for diodes or matched resistors. The half-wave rectifier can have either positive or negative going outputs, depending on the way the circuit is arranged.

### 9.2.2.2 Detailed Design Procedure

In [Figure 32](#) the circuit is referenced to ground, while in [Figure 33](#) the circuit is biased to the positive supply. These configurations implement the half-wave rectifier because the LMV98x-N can not respond to one-half of the incoming waveform. It can not respond to one-half of the incoming because the amplifier cannot swing the output beyond either rail; therefore, the output disengages during this half cycle. During the other half cycle, however, the amplifier achieves a half wave that can have a peak equal to the total supply voltage.  $R_1$  must be large enough not to load the LMV98x-N.

### 9.2.2.3 Application Curves



## 9.2.3 Instrumentation Amplifier With Rail-to-Rail Input and Output Application

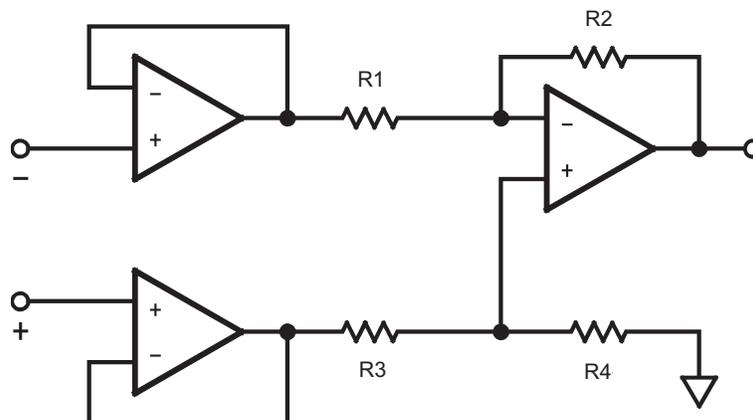


Figure 36. Rail-to-Rail Instrumentation Amplifier

### 9.2.3.1 Design Requirements

Using three of the LMV98x-N amplifiers, an instrumentation amplifier with rail-to-rail inputs and outputs can be made as shown in [Figure 36](#).

### 9.2.3.2 Detailed Design Procedure

In this example, amplifiers on the left side act as buffers to the differential stage. These buffers assure that the input impedance is high. They also assure that the difference amp is driven from a voltage source. This is necessary to maintain the CMRR set by the matching  $R_1$  to  $R_2$  with  $R_3$  to  $R_4$ . The gain is set by the ratio of  $R_2/R_1$  and  $R_3$  must equal  $R_1$  and  $R_4$  equal  $R_2$ . With both rail-to-rail input and output ranges, the input and output are only limited by the supply voltages. Remember that even with rail-to-rail outputs, the output can not swing past the supplies so the combined common-mode voltages plus the signal must not be greater than the supplies or limiting occurs.

## Typical Applications (continued)

### 9.2.3.3 Application Curve

Figure 37 shows the results of the instrumentation amplifier with  $R_1$  and  $R_3 = 1\text{ K}$ , and  $R_2$  and  $R_4 = 100\text{ k}\Omega$ , for a gain of 100, running on a single 5-V supply with a input of  $V_{CM} = V_S/2$ . The combined effects of the individual offset voltages can be seen as a shift in the offset of the curve.

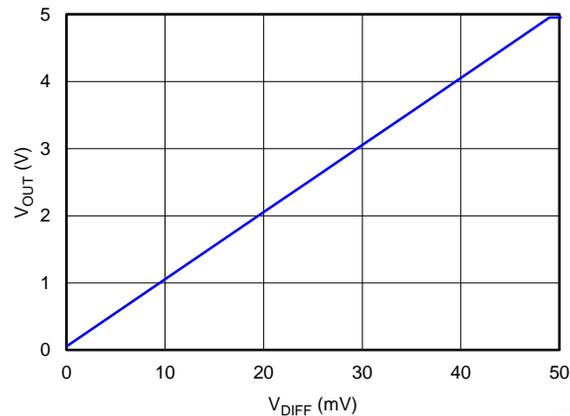


Figure 37. Instrumentation Amplifier Output Results

## 9.3 Do's and Don'ts

Do properly bypass the power supplies.

Do add series resistance to the output when driving capacitive loads, particularly cables, Muxes and ADC inputs.

Do add series current limiting resistors and external schottky clamp diodes if input voltage is expected to exceed the supplies. Limit the current to 1 mA or less (1 k $\Omega$  per volt).

## 10 Power Supply Recommendations

The LMV98x-N is specified for operation from 1.8 V to 5 V; many specifications apply from  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in [Typical Characteristics](#).

### CAUTION

Supply voltages larger than 5.5 V can permanently damage the device; see [Absolute Maximum Ratings](#).

For proper operation, the power supplies must be properly decoupled. For decoupling the supply lines, TI recommends that 10-nF capacitors be placed as close as possible to the op amp power supply pins. For single-supply, place a capacitor between  $V^+$  and  $V^-$  supply leads. For dual supplies, place one capacitor between  $V^+$  and ground, and one capacitor between  $V^-$  and ground.

## 11 Layout

### 11.1 Layout Guidelines

The  $V^+$  pin must be bypassed to ground with a low-ESR capacitor.

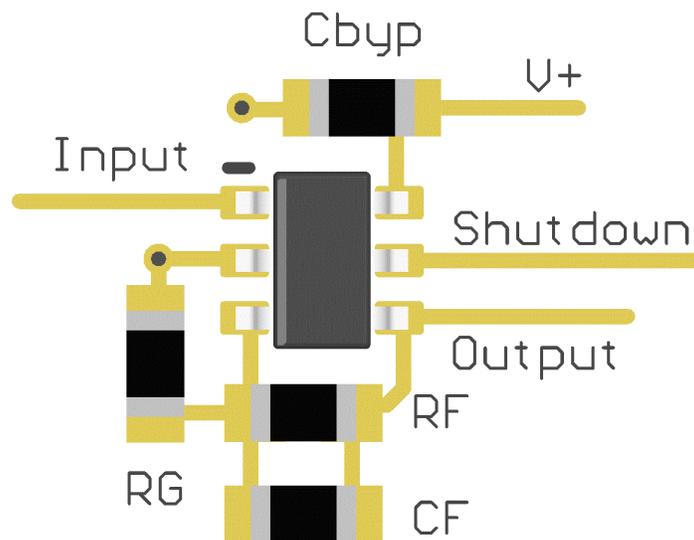
The optimum placement is closest to the  $V^+$  and ground pins.

Take care to minimize the loop area formed by the bypass capacitor connection between  $V^+$  and ground.

The ground pin must be connected to the PCB ground plane at the pin of the device.

The feedback components must be placed as close to the device as possible minimizing strays.

### 11.2 Layout Example



**Figure 38. SOT-23 Layout Example**

## 12 デバイスおよびドキュメントのサポート

### 12.1 ドキュメントのサポート

#### 12.1.1 関連資料

関連資料については、以下を参照してください。

『[ハンダ付けの絶対最大定格](#)』(SNOA549)

### 12.2 関連リンク

次の表に、クイック・アクセス・リンクを示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびサンプル注文またはご購入へのクイック・アクセスが含まれます。

表 1. 関連リンク

製品	プロダクト・フォルダ	サンプルとご購入	技術資料	ツールとソフトウェア	サポートとコミュニティ
LMV981-N	<a href="#">ここをクリック</a>				
LMV982-N	<a href="#">ここをクリック</a>				

### 12.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#)のデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 12.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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### 12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">LMV981MF/NOPB</a>	Active	Production	SOT-23 (DBV)   6	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A78A
LMV981MF/NOPB.A	Active	Production	SOT-23 (DBV)   6	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A78A
<a href="#">LMV981MFX/NOPB</a>	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A78A
LMV981MFX/NOPB.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A78A
<a href="#">LMV981MG/NOPB</a>	Active	Production	SC70 (DCK)   6	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A77
LMV981MG/NOPB.A	Active	Production	SC70 (DCK)   6	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A77
<a href="#">LMV981MGX/NOPB</a>	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A77
LMV981MGX/NOPB.A	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A77
<a href="#">LMV981TL/NOPB</a>	Active	Production	DSBGA (YZR)   6	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	A H
LMV981TL/NOPB.A	Active	Production	DSBGA (YZR)   6	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	A H
<a href="#">LMV981TLX/NOPB</a>	Active	Production	DSBGA (YZR)   6	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	A H
LMV981TLX/NOPB.A	Active	Production	DSBGA (YZR)   6	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	A H
<a href="#">LMV982MM/NOPB</a>	Active	Production	VSSOP (DGS)   10	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A87A
LMV982MM/NOPB.A	Active	Production	VSSOP (DGS)   10	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A87A
<a href="#">LMV982MMX/NOPB</a>	Active	Production	VSSOP (DGS)   10	3500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A87A
LMV982MMX/NOPB.A	Active	Production	VSSOP (DGS)   10	3500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A87A

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV981MF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV981MFX/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV981MG/NOPB	SC70	DCK	6	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV981MGX/NOPB	SC70	DCK	6	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV981TL/NOPB	DSBGA	YZR	6	250	178.0	8.4	1.12	1.63	0.76	4.0	8.0	Q1
LMV981TLX/NOPB	DSBGA	YZR	6	3000	178.0	8.4	1.12	1.63	0.76	4.0	8.0	Q1
LMV982MM/NOPB	VSSOP	DGS	10	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV982MMX/NOPB	VSSOP	DGS	10	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV981MF/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LMV981MFX/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0
LMV981MG/NOPB	SC70	DCK	6	1000	208.0	191.0	35.0
LMV981MGX/NOPB	SC70	DCK	6	3000	208.0	191.0	35.0
LMV981TL/NOPB	DSBGA	YZR	6	250	208.0	191.0	35.0
LMV981TLX/NOPB	DSBGA	YZR	6	3000	208.0	191.0	35.0
LMV982MM/NOPB	VSSOP	DGS	10	1000	208.0	191.0	35.0
LMV982MMX/NOPB	VSSOP	DGS	10	3500	367.0	367.0	35.0

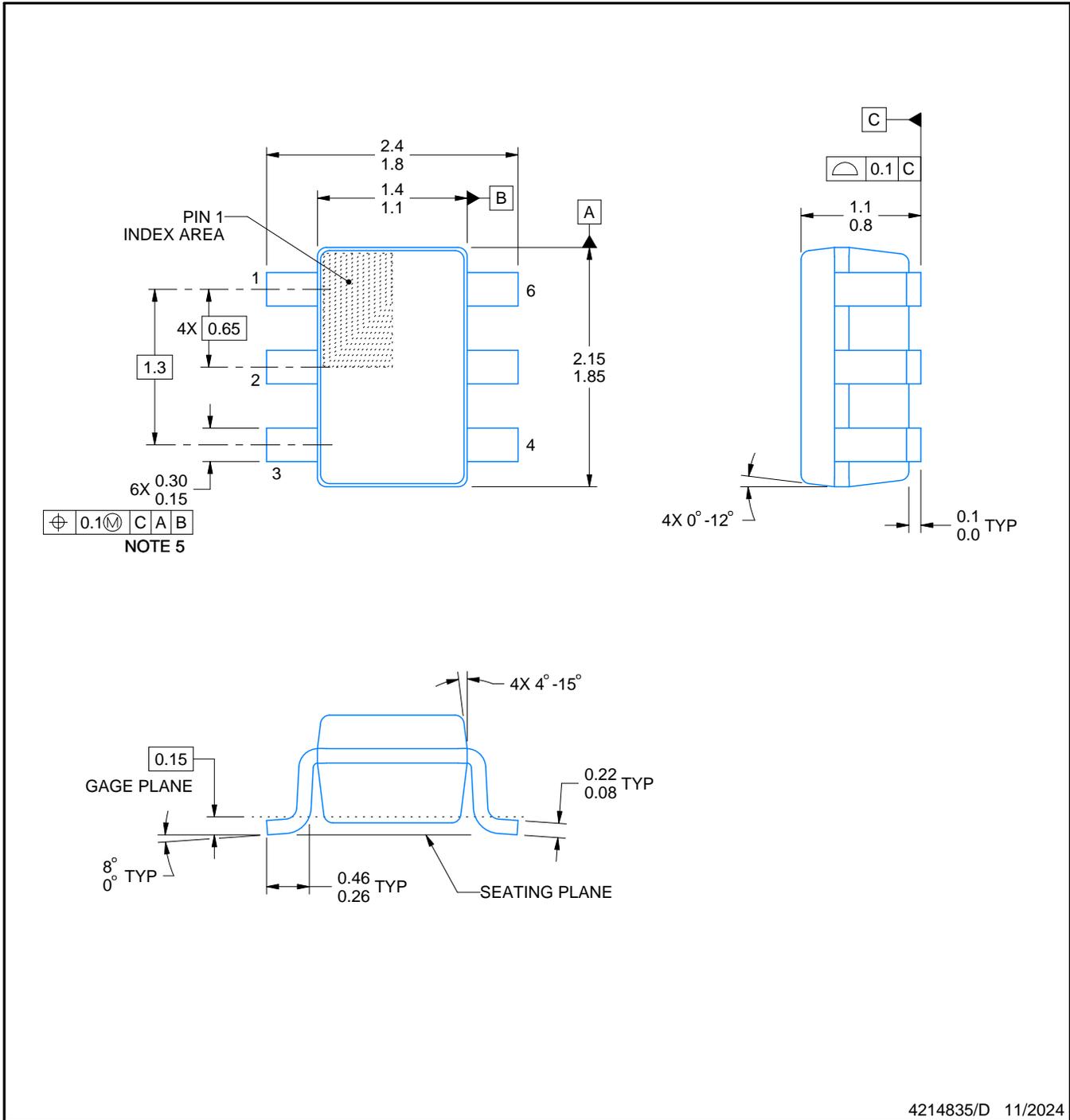
# DCK0006A



# PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR

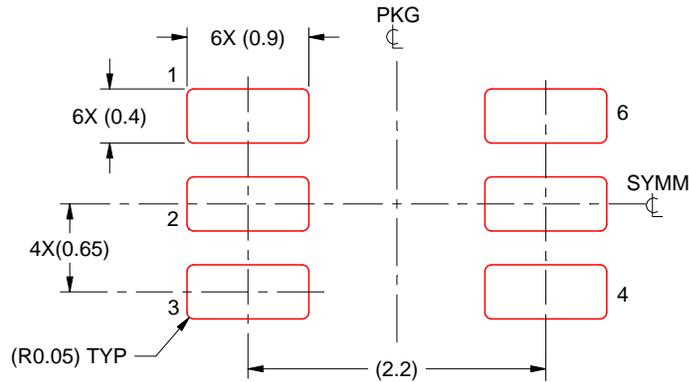


4214835/D 11/2024

**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.





SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

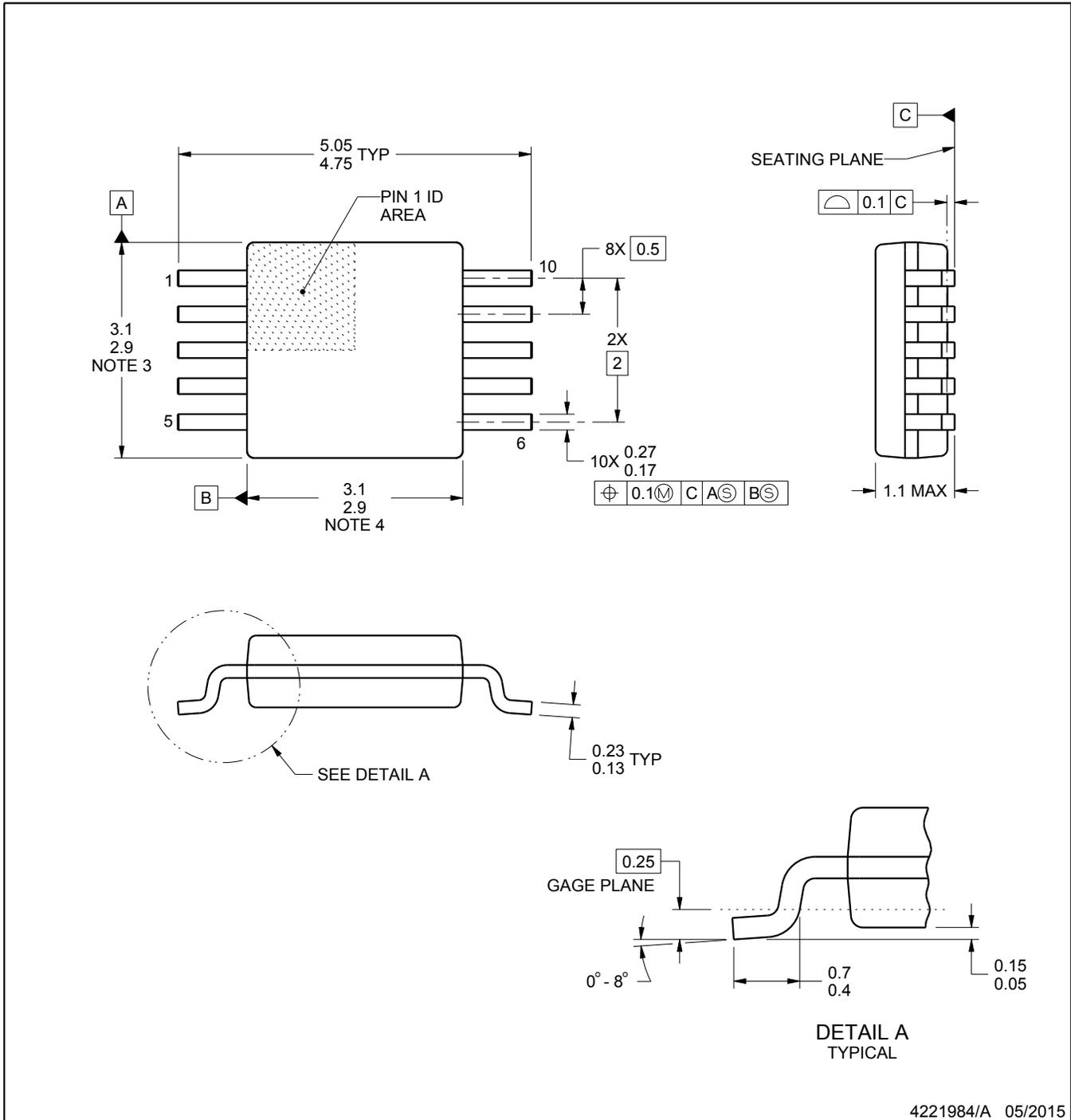
# DGS0010A



# PACKAGE OUTLINE

## VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4221984/A 05/2015

### NOTES:

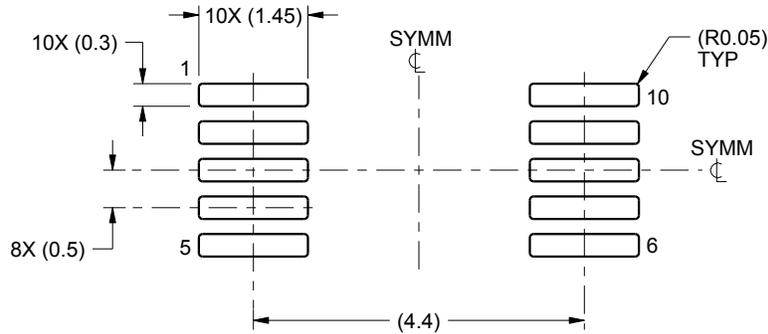
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

# EXAMPLE BOARD LAYOUT

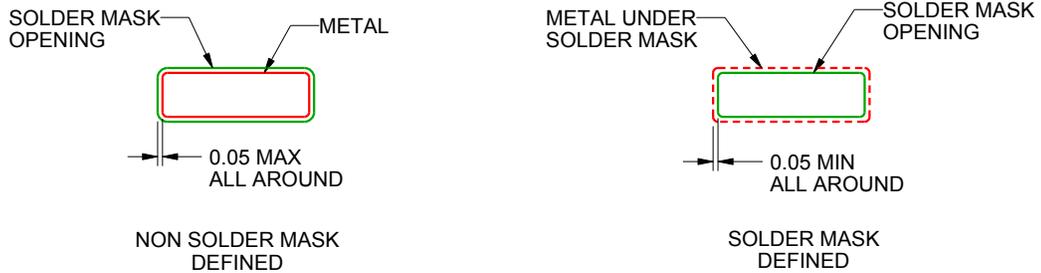
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

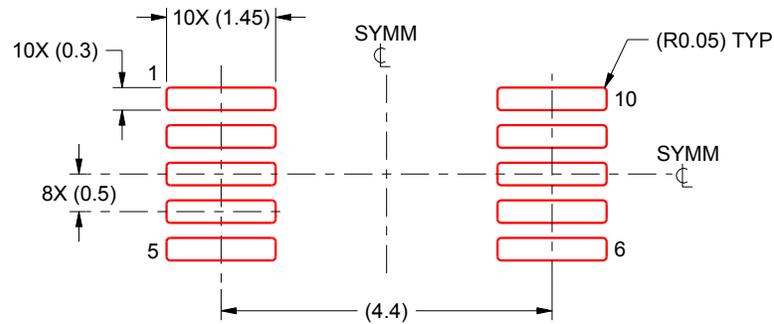
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



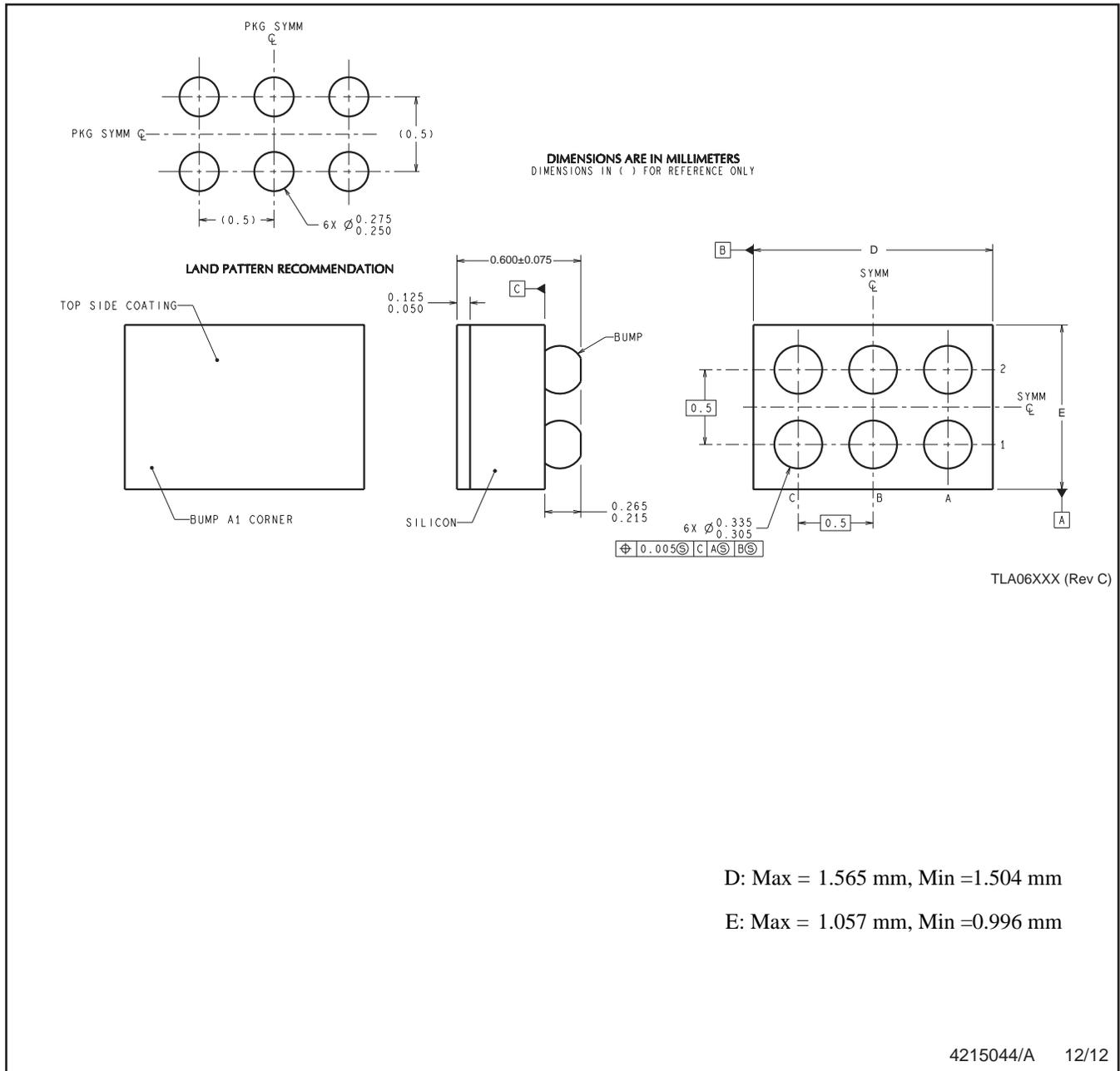
SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

YZR0006



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  
B. This drawing is subject to change without notice.

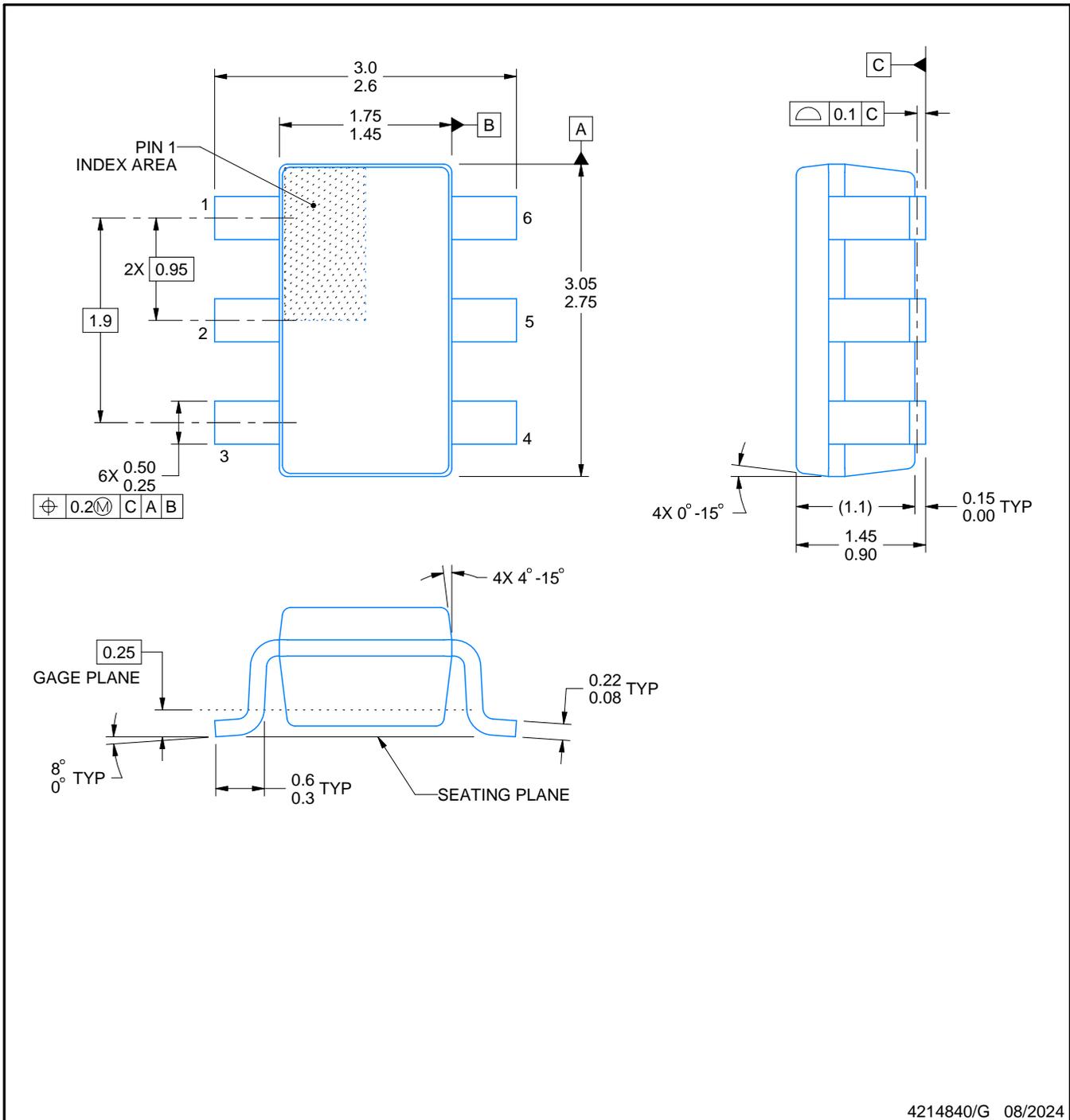
# DBV0006A



## PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214840/G 08/2024

### NOTES:

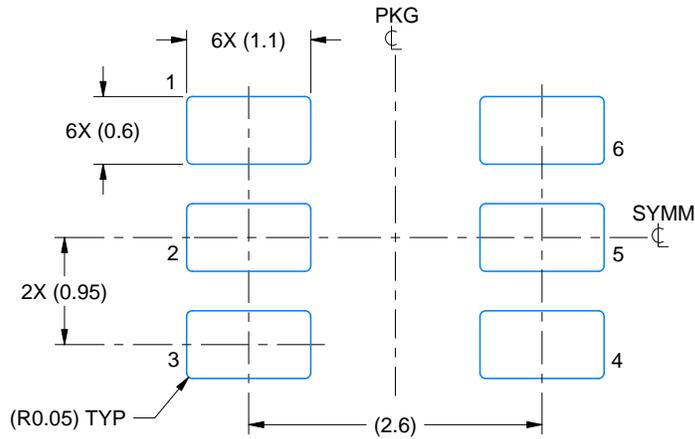
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

# EXAMPLE BOARD LAYOUT

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

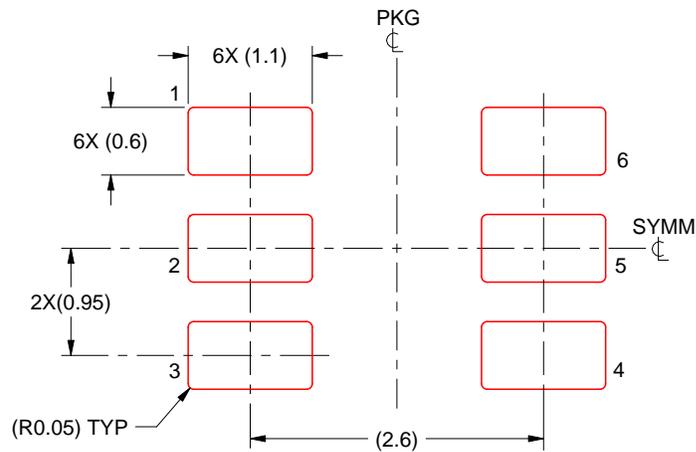
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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